

WHAT IS CLAIMED IS:

1. A film-forming device with a substrate rotating mechanism, which comprises:

a susceptor in the form of a circular disk and provided at
5 the outer periphery with a revolution input section;

a base plate positioned below the susceptor and rotatably retaining the susceptor;

a first rotating mechanism including at least one revolution
generating section, the revolution generating section rotating
10 the susceptor at the outer periphery of the susceptor by way of
imparting a rotating force to the revolution input section;

a plurality of substrate tray retaining sections positioned
circumferentially around a rotation axis of the susceptor;

a plurality of annular substrate trays provided at the outer
15 periphery with a rotation input section and rotatably supported
in the corresponding substrate tray retaining sections;

a second rotating mechanism including a rotation generating
section, the rotation generating section rotating the substrate
trays by way of imparting a rotating force to each rotation input
20 section; and

a plurality of substrates retained in the corresponding
substrate trays, the substrates being revolved by the rotation
of the susceptor and rotated by the rotation of the substrate trays
to apply a certain film-forming process.

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2. A film-forming device with a substrate rotating mechanism according to claim 1, wherein said first rotating mechanism rotatably retains the susceptor via a bearing supported between bearing grooves, each provided at the susceptor and the base plate, and wherein said second rotating mechanism rotatably retains the substrate trays via a bearing supported between bearing grooves, each provided at the substrate trays and the susceptor.

3. A film-forming device with a substrate rotating mechanism according to claim 2, wherein in the first rotating mechanism, the bearing groove of said susceptor and the bearing groove of said base plate are each provided with a horizontal plane and a vertical plane, wherein the bearing groove of said susceptor supports the bearing at an upper support portion and an outer support portion, which position above the bearing and provided in said horizontal and vertical planes, and the bearing groove of the base plate supports the bearing at a lower support portion and an inner support portion, which position below the bearing and provided in said horizontal and vertical planes, and wherein said upper support portion and said lower support portion position at the uppermost position and the lowermost position of the bearing, and the outer support portion and the inner support portion position at both ends of the bearing in the horizontal direction.

4. A film-forming device with a substrate rotating mechanism according to claim 1, wherein each substrate tray retains

the substrate on a substrate support with a film-formation plane of the substrate positioned downward.

5. A film-forming device with a substrate rotating
5 mechanism according to claim 2, wherein each substrate tray retains the substrate on a substrate support with a film-formation plane of the substrate positioned downward.

6. A film-forming device with a substrate rotating
10 mechanism according to claim 3, wherein each substrate tray retains the substrate on a substrate support with a film-formation plane of the substrate positioned downward.

7. A film-forming device with a substrate rotating
15 mechanism according to claim 1 further comprising a temperature control mechanism for adjusting a certain area including the plurality of substrates to a desired temperature distribution, wherein the temperature control mechanism includes at least two temperature control devices, which position both above and below
20 the susceptor or only above the susceptor.

8. A film-forming device with a substrate rotating
mechanism according to claim 2 further comprising a temperature control mechanism for adjusting a certain area including the
25 plurality of substrates to a desired temperature distribution, wherein the temperature control mechanism includes at least two

temperature control devices, which position both above and below the susceptor or only above the susceptor.

9. A film-forming device with a substrate rotating
5 mechanism according to claim 4 further comprising a temperature control mechanism for adjusting a certain area including the plurality of substrates to a desired temperature distribution, wherein the temperature control mechanism includes at least two temperature control devices, which position both above and below
10 the susceptor or only above the susceptor.

10. A film-forming device with a substrate rotating mechanism according to claim 2, wherein the substrate trays, the susceptor and the bearings are made from graphite carbon.

11. A film-forming device with a substrate rotating mechanism according to claim 1, wherein said susceptor is provided at a center portion with an opening, and said opening is covered by a cap member, which is made from the material selected from
20 the group consisting of carbon (C), quartz (SiO_2), molybdenum (Mo), tungsten (W), silicon carbide (SiC), silicon (Si) and gallium arsenide (GaAs).

12. A film-forming device with a substrate rotating
25 mechanism according to claim 1, wherein said certain film-forming process is a thin-film growth by Metal Organic Chemical Vapor

